

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

NPN SILICON PLANAR MEDIUM POWER TRANSISTORS

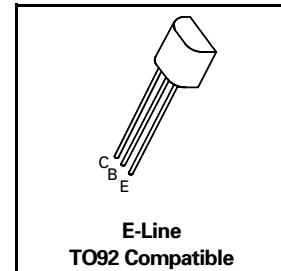
ISSUE 2 – MARCH 1994

FEATURES

- * 60 Volt V_{CEO}
- * 1 Amp continuous current
- * $P_{tot} = 1$ Watt

ZTX450

ZTX451



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | ZTX450 | | ZTX451 | | UNIT |
|---|----------------|-------------|--|-------------|--|------|
| Collector-Base Voltage | V_{CBO} | 60 | | 80 | | V |
| Collector-Emitter Voltage | V_{CEO} | 45 | | 60 | | V |
| Emitter-Base Voltage | V_{EBO} | 5 | | 5 | | V |
| Peak Pulse Current | I_{CM} | 2 | | 2 | | A |
| Continuous Collector Current | I_C | 1 | | 1 | | A |
| Power Dissipation at $T_{amb}=25^\circ C$ | P_{tot} | 1 | | 1 | | W |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +200 | | -55 to +200 | | °C |

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$).

| PARAMETER | SYMBOL | ZTX450 | | ZTX451 | | UNIT | CONDITIONS. |
|---------------------------------------|----------------|-----------|------|----------|------|---------|---|
| | | MIN. | MAX. | MIN. | MAX. | | |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | 60 | | 80 | | V | $I_C=100\mu A$ |
| Collector-Emitter Sustaining Voltage | $V_{CEO(sus)}$ | 45 | | 60 | | V | $I_C=10mA^*$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | 5 | | 5 | | V | $I_E=100\mu A$ |
| Collector Cut-Off Current | I_{CBO} | | 0.1 | | 0.1 | μA | $V_{CB}=45V$ $V_{CB}=60V$ |
| Emitter Cut-Off Current | I_{EBO} | | 0.1 | | 0.1 | μA | $V_{EB}=4V$ |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | | 0.25 | | 0.35 | V | $I_C=150mA$, $I_B=15mA^*$ |
| Base-Emitter Saturation Voltage | $V_{BE(sat)}$ | | 1.1 | | 1.1 | V | $I_C=150mA$, $I_B=15mA^*$ |
| Static Forward Current Transfer Ratio | h_{FE} | 100 15 | 300 | 50 10 | 150 | | $I_C=150mA$, $V_{CE}=10V^*$ $I_C=1A$, $V_{CE}=10V^*$ |
| Transition Frequency | f_T | 150 | | 150 | | MHz | $I_C=50mA$, $V_{CE}=10V$ $f=100MHz$ |
| Output Capacitance | C_{obo} | | 15 | | 15 | pF | $V_{CB}=10V$, $f=1MHz$ |

ZTX450

ZTX451

TYPICAL CHARACTERISTICS

